

BU900TP

NPN power TRILINTON

Preliminary Data

Features

- Integrated high voltage active clamping zener
- Integrated antiparallel collector-emitter diode
- Clamping energy capability 100% tested
- Very high current gain

Applications

- Engine ignition control
- Switching regulators
- Motor control
- Light ballast



Description

The BU900TP is a planar, monolithic, high voltage power Trilinton with a built-in active zener clamping circuit and an antiparallel Collector to Emitter diode. This device has been specifically designed for unclamped, inductive applications such as Ignition systems, Switching Regulators, and wherever high voltage and high robustness is required.

Figure 1. Internal schematic diagram

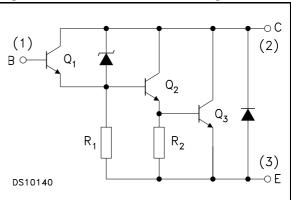


Table 1. Device summary

	Part Number	Marking	Package	Packing	
Ī	BU900TP	BU900TP	SOT-82	Tube	

Electrical ratings BU900TP

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{(BR)CES}	Collector-emitter breakdown voltage (V _{BE} = 0)	370	V
V _{EBO}	Emitter-base voltage (I _C = 0)	8	V
I _C	Collector current	5	Α
I _{CM}	Collector peak current (t _P < 5ms)	8	Α
I _B	Base current	1	Α
P _{tot}	Total dissipation at T _c = 25°C	55	W
T _{stg} Storage temperature		-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case	2.27	°C/W
R _{thj-amb}	Thermal resistance junction-ambient	80	°C/W

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 8 V			100	μА
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 370 V			100	μА
V _{(BR)CES}	Collector-emitter breakdown voltage (V _{BE} = 0)	I _C = 50 mA	370		660	V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 2.5 \text{ A}$ $I_B = 1 \text{ mA}$ $I_C = 3 \text{ A}$ $I_B = 3 \text{ mA}$			4 4	V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = 3 \text{ A}$ $I_B = 3 \text{ mA}$			3.5	V
h _{FE}	DC current gain	$I_C = 1 A$ $V_{CE} = 5 V$	7000			
V _F	Diode forward voltage	I _C = 5 A			18	V
E _{s/b} (1)	Secondary breakdown energy	I _C = 4 A L = 10 mH	80			mJ

^{1.} Pulsed duration = 300 ms, duty cycle ⊴.5%

Electrical characteristics BU900TP

2.1 Electrical characteristics (curves)

Figure 2. DC current gain

100000 80000 40000 10⁻¹
2 4 6 8 10⁰
2 4 6 8 10⁰
2 4 6 8 10⁰
2 6 8 10⁰
3 6 8 10⁰
4 7 10⁰
4 7 10⁰
4 8 10⁰
8 10

Figure 3. Collector-emitter saturation voltage

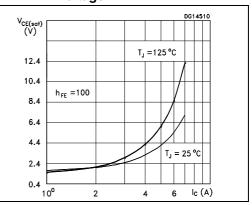


Figure 4. Collector-emitter saturation voltage

V_{CE(sot)} (V)

16.4

14.4

12.4

10.4

8.4

6.4

4.4

2.4

0.4

10°

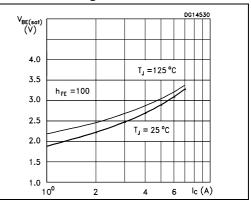
2

4

6

IC (A)

Figure 5. Base-emitter saturation voltage



4/8

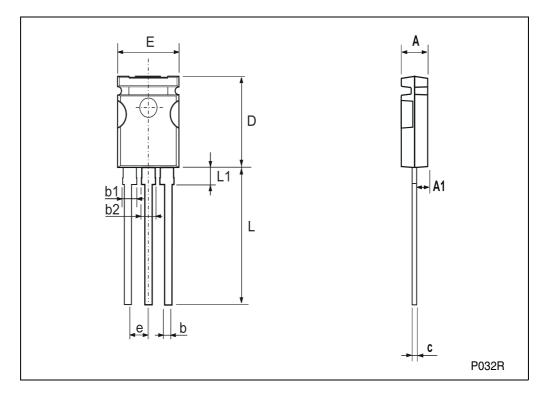
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

577

SOT-82FM MECHANICAL DATA

DIM.	mm			inch		
Diiii.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	2.85		3.05	1.122		1.200
A1	1.47		1.67	0.578		0.657
b	0.40		0.60	0.157		0.236
b1	1.4		1.6	0.551		0.630
b2	1.3		1.5	0.511		0.590
С	0.45		0.6	0.177		0.236
D	10.5		10.9	4.133		4.291
е	2.2		2.8	0.866		1.102
E	7.45		7.75	2.933		3.051
L	15.5		15.9	6.102		6.260
L1	1.95		2.35	0.767		0.925



BU900TP Revision history

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
02-Aug-2007	1	First release.

47/

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577